ON Semiconductor

Is Now

onsemi™

To learn more about onsemi™, please visit our website at
www.onsemi.com

CAT28C16A

16 kb CMOS Parallel EEPROM

Description

The CAT28C16A is a fast, low power, 5V−only CMOS Parallel EEPROM organized as 2K x 8−bits. It requires a simple interface for in−system programming. On−chip address and data latches, self−timed write cycle with auto−clear and V_{CC} power up/down write protection eliminate additional timing and protection hardware. $\overline{DATA}$ Polling signals the start and end of the self−timed write cycle. Additionally, the CAT28C16A features hardware write protection.
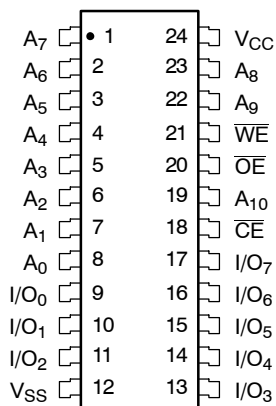
The CAT28C16A is manufactured using ON Semiconductor's advanced CMOS floating gate technology. It is designed to endure 100,000 program/erase cycles and has a data retention of 100 years. The device is available in JEDEC approved 24−pin DIP and SOIC or 32−pin PLCC packages.
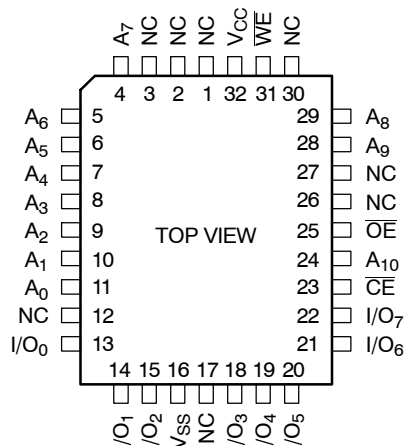
Features

- Fast Read Access Times: 90 ns, 120 ns, 200 ns
- Low Power CMOS Dissipation:
  – Active: 25 mA Max.
  – Standby: 100 μA Max.
- Simple Write Operation:
  – On−chip Address and Data Latches
  – Self−timed Write Cycle with Auto−clear
- Fast Write Cycle Time: 10 ms Max
- End of Write Detection: $\overline{DATA}$ Polling
- Hardware Write Protection
- CMOS and TTL Compatible I/O
- 100,000 Program/Erase Cycles
- 100 Year Data Retention
- Commercial, Industrial and Automotive Temperature Ranges

ON Semiconductor®

http://onsemi.com

SOIC−24
J, K, W, X SUFFIX
CASE 751BK
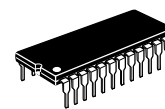
PDIP−24
L SUFFIX
CASE 646AD
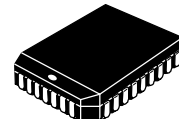
PLCC−32
N, G SUFFIX
CASE 776AK

PIN FUNCTION

Pin Name	Function
A_0–A_{10}	Address Inputs
I/O_0–I/O_7	Data Inputs/Outputs
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
$\overline{WE}$	Write Enable
V_{CC}	5 V Supply
V_{SS}	Ground
NC	No Connect

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

PIN CONFIGURATION

DIP Package (L)
SOIC Package (J, K, W, X)

A_7	1	24	V_{CC}
A_6	2	23	A_8
A_5	3	22	A_9
A_4	4	21	$\overline{WE}$
A_3	5	20	$\overline{OE}$
A_2	6	19	A_{10}
A_1	7	18	$\overline{CE}$
A_0	8	17	I/O_7
I/O_0	9	16	I/O_6
I/O_1	10	15	I/O_5
I/O_2	11	14	I/O_4
V_{SS}	12	13	I/O_3

PLCC Package (N, G)

TOP VIEW

Top pins: A_7 (4), NC (3), NC (2), NC (1), V_{CC} (32), $\overline{WE}$ (31), NC (30)

Left pins: A_6 (5), A_5 (6), A_4 (7), A_3 (8), A_2 (9), A_1 (10), A_0 (11), NC (12), I/O_0 (13)

Right pins: A_8 (29), A_9 (28), NC (27), NC (26), $\overline{OE}$ (25), A_{10} (24), $\overline{CE}$ (23), I/O_7 (22), I/O_6 (21)

Bottom pins: I/O_1 (14), I/O_2 (15), V_{SS} (16), NC (17), I/O_3 (18), I/O_4 (19), I/O_5 (20)

1

CAT28C16A

Figure 1. Block Diagram

Table 1. MODE SELECTION

Mode	$\overline{CE}$	$\overline{WE}$	$\overline{OE}$	I/O	Power
Read	L	H	L	D_{OUT}	ACTIVE
Byte Write ($\overline{WE}$ Controlled)	L	$\underline{\vee}$	H	D_{IN}	ACTIVE
Byte Write ($\overline{CE}$ Controlled)	$\underline{\vee}$	L	H	D_{IN}	ACTIVE
Standby, and Write Inhibit	H	X	X	High–Z	STANDBY
Read and Write Inhibit	X	H	H	High–Z	ACTIVE

Table 2. CAPACITANCE (T_A = 25°C, f = 1.0 MHz, V_{CC} = 5 V)

Symbol	Test	Max	Conditions	Units
$C_{I/O}$ (Note 1)	Input/Output Capacitance	10	$V_{I/O}$ = 0 V	pF
C_{IN} (Note 1)	Input Capacitance	6	V_{IN} = 0 V	pF

1. This parameter is tested initially and after a design or process change that affects the parameter.

Table 3. ABSOLUTE MAXIMUM RATINGS

Parameters	Ratings	Units
Temperature Under Bias	−55 to +125	°C
Storage Temperature	−65 to +150	°C
Voltage on Any Pin with Respect to Ground (Note 2)	−2.0 V to +V_{CC} + 2.0 V	V
V_{CC} with Respect to Ground	−2.0 to +7.0	V
Package Power Dissipation Capability (T_A = 25°C)	1.0	W
Lead Soldering Temperature (10 secs)	300	°C
Output Short Circuit Current (Note 3)	100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
2. The minimum DC input voltage is −0.5 V. During transitions, inputs may undershoot to −2.0 V for periods of less than 20 ns. Maximum DC voltage on output pins is V_{CC} + 0.5 V, which may overshoot to V_{CC} + 2.0 V for periods of less than 20 ns.
3. Output shorted for no more than one second. No more than one output shorted at a time.

Table 4. RELIABILITY CHARACTERISTICS (Note 4)

Symbol	Parameter	Min	Max	Units
N_{END} (Note 5)	Endurance	100,000		Cycles/Byte
T_{DR} (Notes 5)	Data Retention	100		Years
V_{ZAP}	ESD Susceptibility	2,000		V
I_{LTH} (Note 6)	Latch−Up	100		mA

4. This parameter is tested initially and after a design or process change that affects the parameter.
5. For the CAT28C16A−20, the minimum endurance is 10,000 cycles and the minimum data retention is 10 years.
6. Latch−up protection is provided for stresses up to 100 mA on address and data pins from −1 V to V_{CC} + 1 V.

Table 5. D.C. OPERATING CHARACTERISTICS (V_{CC} = 5 V ±10%, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
I_{CC}	V_{CC} Current (Operating, TTL)	$\overline{CE} = \overline{OE} = V_{IL}$, f = 1/$t_{RC}$ min, All I/O's Open			35	mA
I_{CCC} (Note 7)	V_{CC} Current (Operating, CMOS)	$\overline{CE} = \overline{OE} = V_{ILC}$, f = 1/$t_{RC}$ min, All I/O's Open			25	mA
I_{SB}	V_{CC} Current (Standby, TTL)	$\overline{CE} = V_{IH}$, All I/O's Open			1	mA
I_{SBC} (Note 8)	V_{CC} Current (Standby, CMOS)	$\overline{CE} = V_{IHC}$, All I/O's Open			100	μA
I_{LI}	Input Leakage Current	V_{IN} = GND to V_{CC}	−10		10	μA
I_{LO}	Output Leakage Current	V_{OUT} = GND to V_{CC}, $\overline{CE} = V_{IH}$	−10		10	μA
V_{IH} (Note 8)	High Level Input Voltage		2		V_{CC} + 0.3	V
V_{IL} (Note 7)	Low Level Input Voltage		−0.3		0.8	V
V_{OH}	High Level Output Voltage	I_{OH} = −400 μA	2.4			V
V_{OL}	Low Level Output Voltage	I_{OL} = 2.1 mA			0.4	V
V_{WI}	Write Inhibit Voltage		3.0			V

7. V_{ILC} = −0.3 V to +0.3 V
8. V_{IHC} = V_{CC} − 0.3 V to V_{CC} + 0.3 V

Table 6. A.C. CHARACTERISTICS, READ CYCLE (V_{CC} = 5 V ±10%, unless otherwise specified.)

Symbol	Parameter	28C16A−90 Min	28C16A−90 Max	28C16A−12 Min	28C16A−12 Max	28C16A−20 Min	28C16A−20 Max	Units
t_{RC}	Read Cycle Time	90		120		200		ns
t_{CE}	$\overline{CE}$ Access Time		90		120		200	ns
t_{AA}	Address Access Time		90		120		200	ns
t_{OE}	$\overline{OE}$ Access Time		50		60		80	ns
t_{LZ} (Note 9)	$\overline{CE}$ Low to Active Output	0		0		0		ns
t_{OLZ} (Note 9)	$\overline{OE}$ Low to Active Output	0		0		0		ns
t_{HZ} (Notes 9, 10)	$\overline{CE}$ High to High−Z Output		50		50		55	ns
t_{OHZ} (Notes 9, 10)	$\overline{OE}$ High to High−Z Output		50		50		55	ns
t_{OH} (Note 9)	Output Hold from Address Change	0		0		0		ns

9. This parameter is tested initially and after a design or process change that affects the parameter.
10. Output floating (High−Z) is defined as the state when the external data line is no longer driven by the output buffer.

2.4 V ─────────────
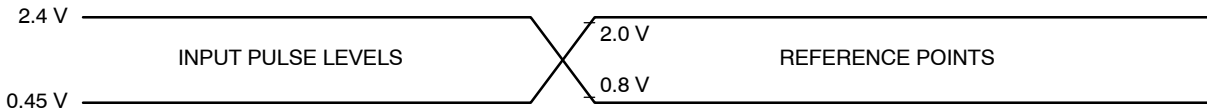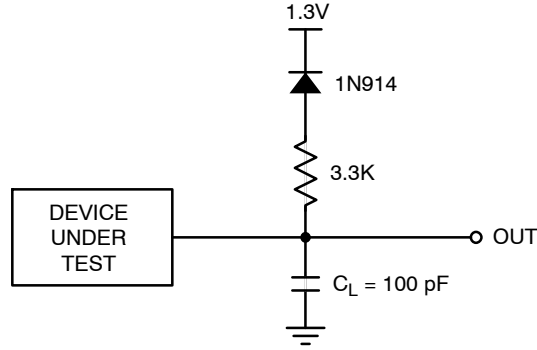0.45 V ────────────

INPUT PULSE LEVELS

2.0 V
0.8 V

REFERENCE POINTS

Figure 2. A.C. Testing Input/Output Waveform (Note 11)

11. Input rise and fall times (10% and 90%) < 10 ns.

1.3V

1N914

3.3K

DEVICE
UNDER
TEST

OUT

C_L = 100 pF

C_L INCLUDES JIG CAPACITANCE

Figure 3. A.C. Testing Load Circuit (example)

Table 7. A.C. CHARACTERISTICS, WRITE CYCLE (V_{CC} = 5 V ±10%, unless otherwise specified.)

Symbol	Parameter	28C16A–90		28C16A–12		28C16A–20		Units
		Min	Max	Min	Max	Min	Max	
t_{WC}	Write Cycle Time		5		5		10	ms
t_{AS}	Address Setup Time	0		0		10		ns
t_{AH}	Address Hold Time	100		100		100		ns
t_{CS}	$\overline{CE}$ Setup Time	0		0		0		ns
t_{CH}	$\overline{CE}$ Hold Time	0		0		0		ns
t_{CW} (Note 12)	$\overline{CE}$ Pulse Time	110		110		150		ns
t_{OES}	$\overline{OE}$ Setup Time	0		0		15		ns
t_{OEH}	$\overline{OE}$ Hold Time	0		0		15		ns
t_{WP} (Note 12)	$\overline{WE}$ Pulse Width	110		110		150		ns
t_{DS}	Data Setup Time	60		60		50		ns
t_{DH}	Data Hold Time	0		0		10		ns
t_{DL}	Data Latch Time	5	10	5	10	50		ns
t_{INIT} (Note 13)	Write Inhibit Period After Power–up	0.05	100	0.05	100	5	20	ms

12. A write pulse of less than 20 ns duration will not initiate a write cycle.
13. This parameter is tested initially and after a design or process change that affects the parameter.

CAT28C16A

DEVICE OPERATION

Read

Data stored in the CAT28C16A is transferred to the data bus when $\overline{WE}$ is held high, and both $\overline{OE}$ and $\overline{CE}$ are held low. The data bus is set to a high impedance state when either $\overline{CE}$ or $\overline{OE}$ goes high. This 2−line control architecture can be used to eliminate bus contention in a system environment.
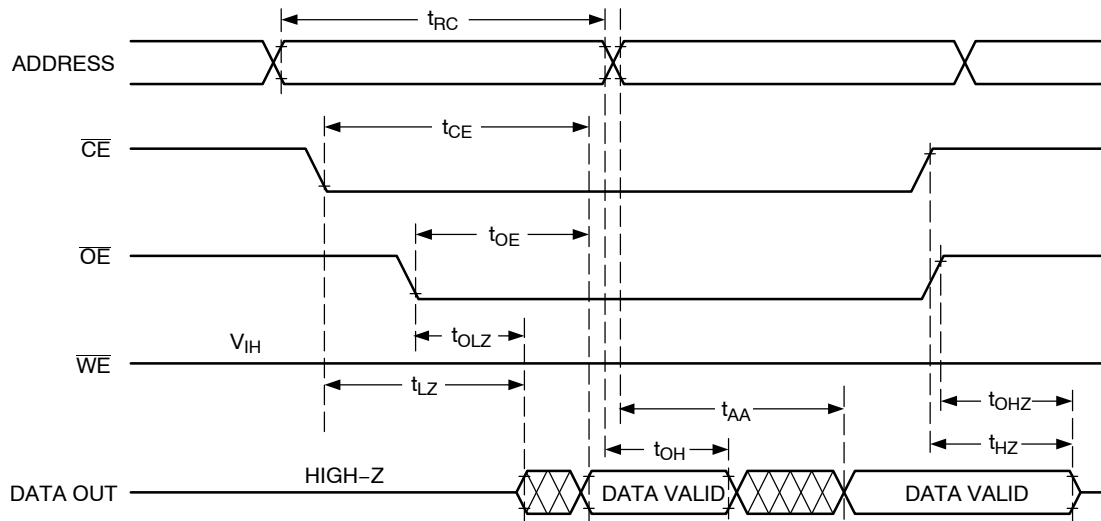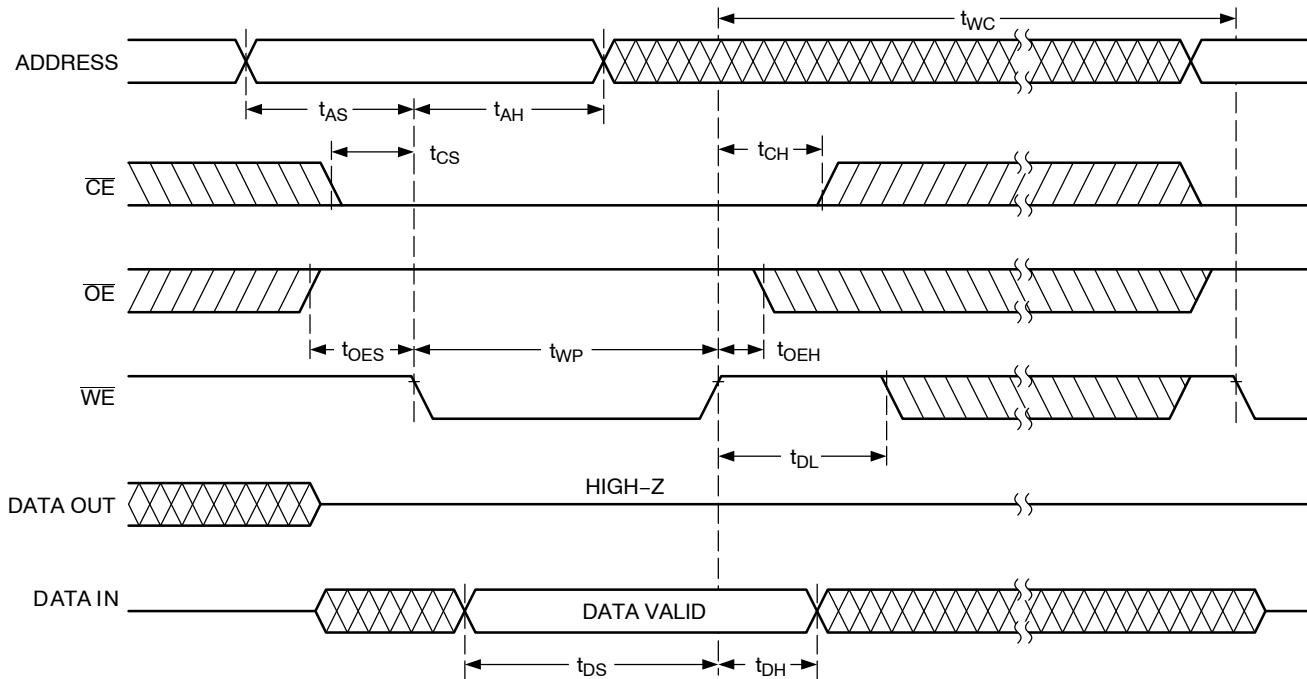

Figure 4. Read Cycle

Figure 5. Byte Write Cycle [$\overline{WE}$ Controlled]

Byte Write

A write cycle is executed when both $\overline{CE}$ and $\overline{WE}$ are low, and $\overline{OE}$ is high. Write cycles can be initiated using either $\overline{WE}$ or $\overline{CE}$, with the address input being latched on the falling edge of $\overline{WE}$ or $\overline{CE}$, whichever occurs last. Data, conversely, is latched on the rising edge of $\overline{WE}$ or $\overline{CE}$, whichever occurs first. Once initiated, a byte write cycle automatically erases the addressed byte and the new data is written within 10 ms.

CAT28C16A

$\overline{\text{DATA}}$ Polling

$\overline{\text{DATA}}$ polling is provided to indicate the completion of a byte write cycle. Once a byte write cycle is initiated, attempting to read the last byte written will output the complement of that data on I/O_7 (I/O_0–I/O_6 are indeterminate) until the programming cycle is complete. Upon completion of the self–timed byte write cycle, all I/O's will output true data during a read cycle.
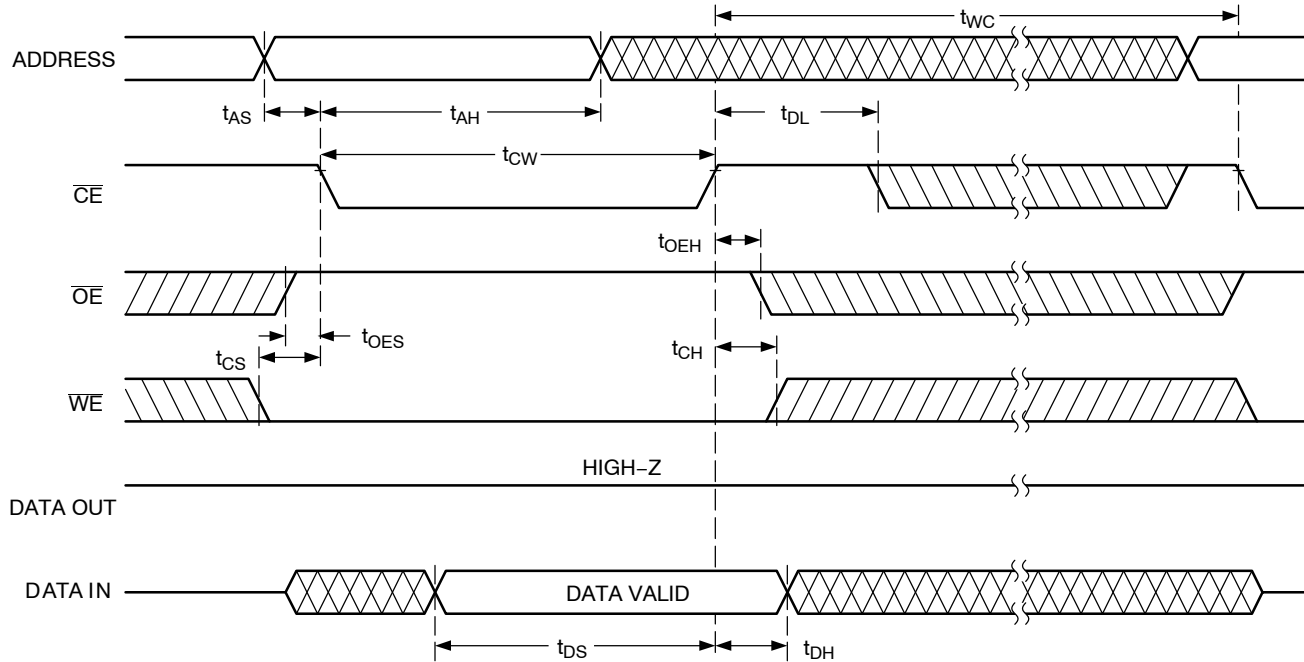
Figure 6. Byte Write Cycle [$\overline{\text{CE}}$ Controlled]
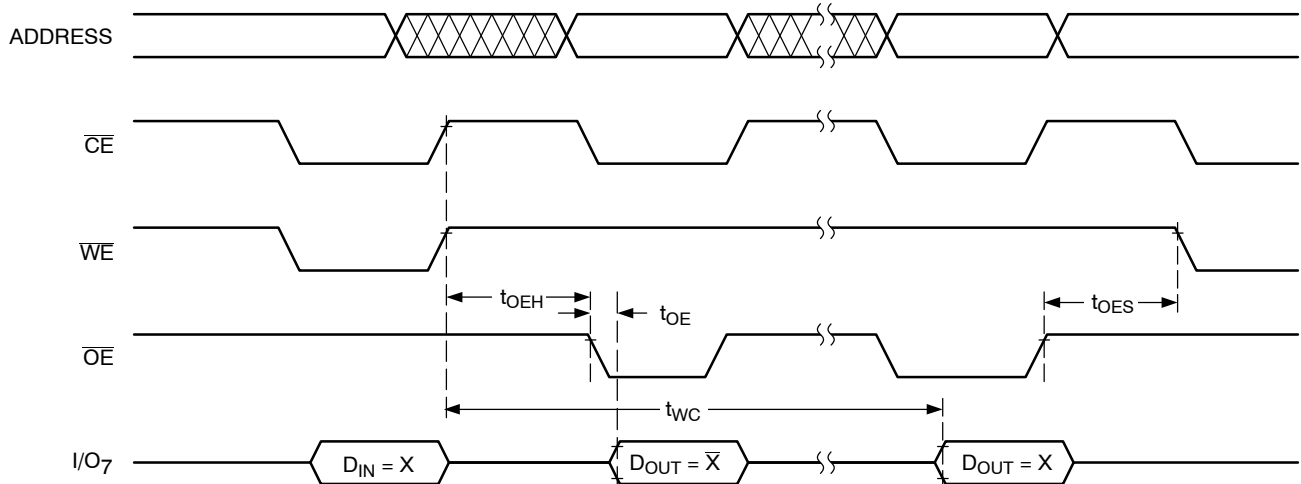
Figure 7. $\overline{\text{DATA}}$ Polling

Hardware Data Protection

The following is a list of hardware data protection features that are incorporated into the CAT28C16A.

1. V_{CC} sense provides for write protection when V_{CC} falls below 3.0 V min.
2. A power on delay mechanism, t_{INIT} (see AC characteristics), provides a 5 to 20 ms delay before a write sequence, after V_{CC} has reached 3.0 V min.
3. Write inhibit is activated by holding any one of $\overline{\text{OE}}$ low, $\overline{\text{CE}}$ high or $\overline{\text{WE}}$ high.
4. Noise pulses of less than 20 ns on the $\overline{\text{WE}}$ or $\overline{\text{CE}}$ inputs will not result in a write cycle.

CAT28C16A

PACKAGE DIMENSIONS

PLCC 32
CASE 776AK–01
ISSUE O

PIN#1 IDENTIFICATION
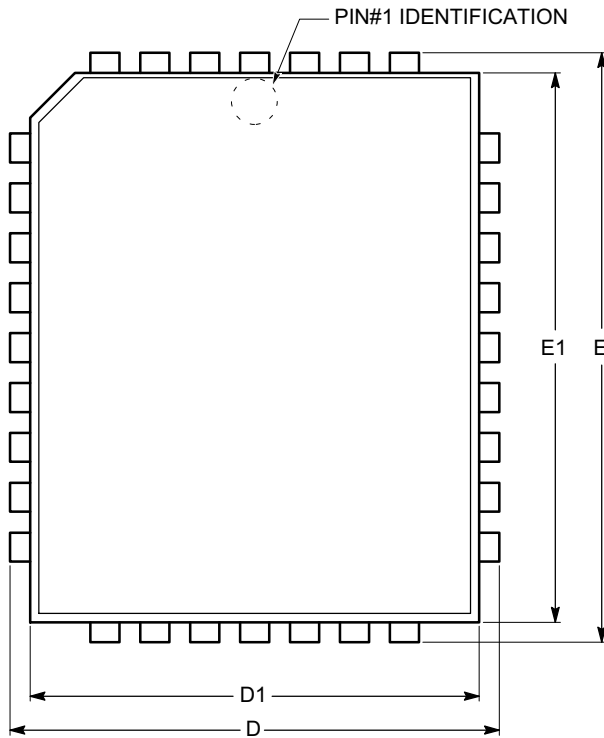
TOP VIEW
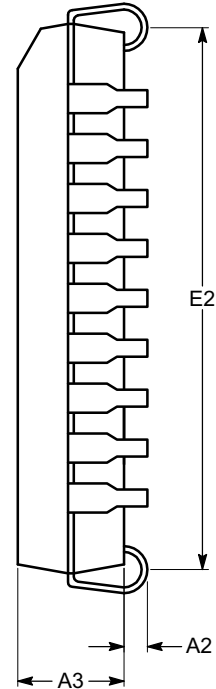
END VIEW
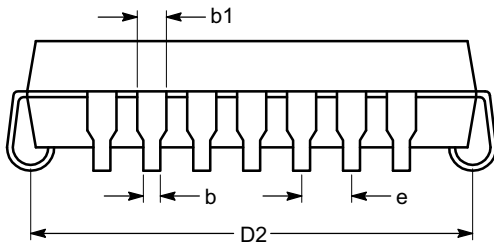
SIDE VIEW

Notes:

(1) All dimensions are in millimeters.
(2) Complies with JEDEC MS-016.

SYMBOL	MIN	NOM	MAX
A2	0.38		
A3	2.54		2.80
b	0.33		0.54
b1	0.66		0.82
D	12.32		12.57
D1	11.36		11.50
D2	9.56		11.32
E	14.86		15.11
E1	13.90		14.04
E2	12.10		13.86
e	1.27 BSC		

CAT28C16A

PACKAGE DIMENSIONS

SOIC−24, 300 mils
CASE 751BK−01
ISSUE O

TOP VIEW

PIN#1 IDENTIFICATION
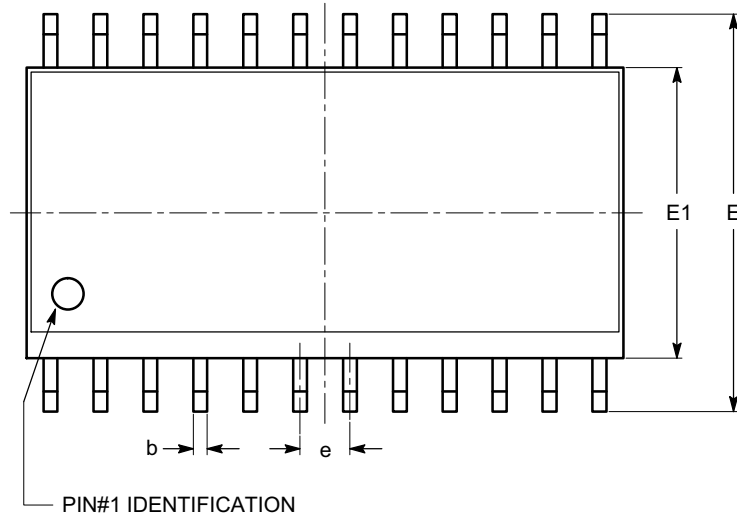
SYMBOL	MIN	NOM	MAX
A	2.35		2.65
A1	0.10		0.30
A2	2.05		2.55
b	0.31		0.51
c	0.20		0.33
D	15.20		15.40
E	10.11		10.51
E1	7.34		7.60
e		1.27 BSC	
h	0.25		0.75
L	0.40		1.27
θ	0º		8º
θ1	5º		15º
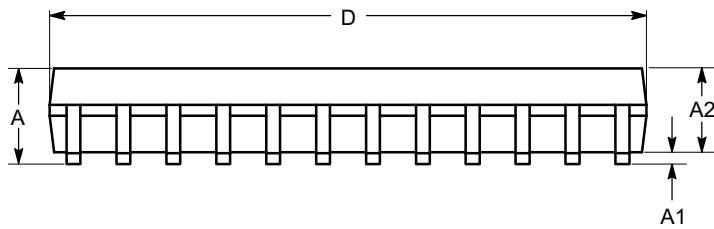
SIDE VIEW
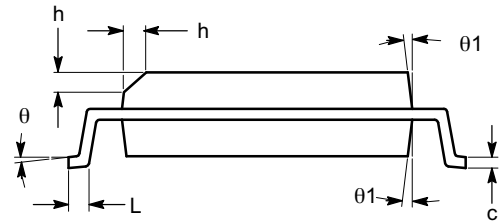
END VIEW

Notes:

(1) All dimensions are in millimeters. Angles in degrees.
(2) Complies with JEDEC MS-013.

CAT28C16A

PACKAGE DIMENSIONS

PDIP−24, 600 mils
CASE 646AD−01
ISSUE A
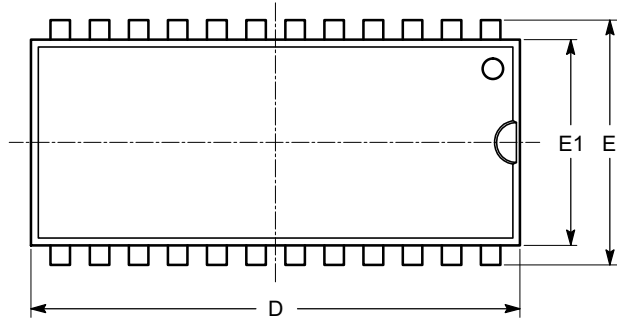
TOP VIEW

SIDE VIEW

END VIEW

SYMBOL	MIN	NOM	MAX
A			6.35
A1	0.39		
A2	3.18		4.95
b	0.36		0.55
b1	0.77		1.77
c	0.21		0.38
D	31.50		32.25
E	15.24		15.87
E1	12.32		14.73
e		2.54 BSC	
eB	15.24		17.78
L	2.93		5.08
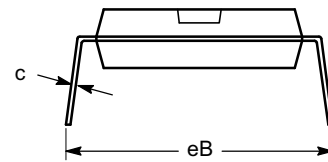
Notes:

(1) All dimensions are in millimeters.
(2) Complies with JEDEC MS-011.

CAT28C16A

Example of Ordering Information

Prefix	Device #	Suffix

CAT   28C16A   N   I   – 20   T

Company ID (Optional)

Product Number
28C16A

Temperature Range
Blank = Commercial (0°C to +70°C)
I = Industrial (−40°C to +85°C)
A = Automotive (−40°C to +105°C)

Speed
−90: 90 ns
−12: 120 ns
−20: 200 ns

Tape & Reel (Note 15)
T: Tape & Reel

Package
N: PLCC
J: SOIC (JEDEC)
K: SOIC (EIAJ)
L: PDIP (Lead Free, Halogen Free)
G: PLCC (Lead Free, Halogen Free)
W: SOIC (JEDEC) (Lead Free, Halogen Free)
X: SOIC (EIAJ) (Lead Free, Halogen Free)

14. The device used in the above example is a CAT28C16ANI−20T (PLCC, Industrial Temperature, 200 ns Access Time, Tape & Reel).
15. For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.